



N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
	90mΩ @ V _{GS} = 4.5V	4.2A
20V	120mΩ @ V _{GS} = 2.5V	2.7A

Description and Applications

This MOSFET is designed to minimize the on-state resistance $(R_{DS(on)})$ and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- General Purpose Interfacing Switch
- Power Management Functions
- Boost Application
- Analog Switch

Features

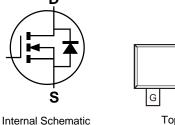
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (Approximate)



Top View



Top View

S

D

Ordering Information (Note 5)

Part Number	Case	Packaging
DMG2302UQ-7	SOT-23	3,000/Tape & Reel
DMG2302UQ-13	SOT-23	10,000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

G

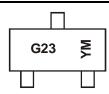
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_grade_definitions/.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



G23 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: C = 2015) M = Month (ex: 9 = September)

Date Code Key

Notes:

Date Obuc Rey												
Year	2009	2010	2011	2012	2 201	13 20	014 2	2015	2016	2017	2018	2019
Code	W	Х	Y	Z	A		В	С	D	E	F	G
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



Maximum Ratings (@T_A = +25°C unless otherwise specified.)

Characte	eristic		Symbol	Value	Units
Drain-Source Voltage			V _{DSS}	20	V
Gate-Source Voltage		V _{GSS}	±8	V	
Continuous Drain Current (Note 6)Steady State $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$			۱ _D	4.2 3.4	А
Pulsed Drain Current (Note 7)		I _{DM}	27	А	

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Power Dissipation (Note 6)	T _A = +25°C T _A = +70°C		0.8 0.5	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$	R _{θJA}	156	°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

Notes: 6. Device mounted on FR-4 PCB, with minimum recommended pad layout. 7. Repetitive rating, pulse width limited by junction temperature.

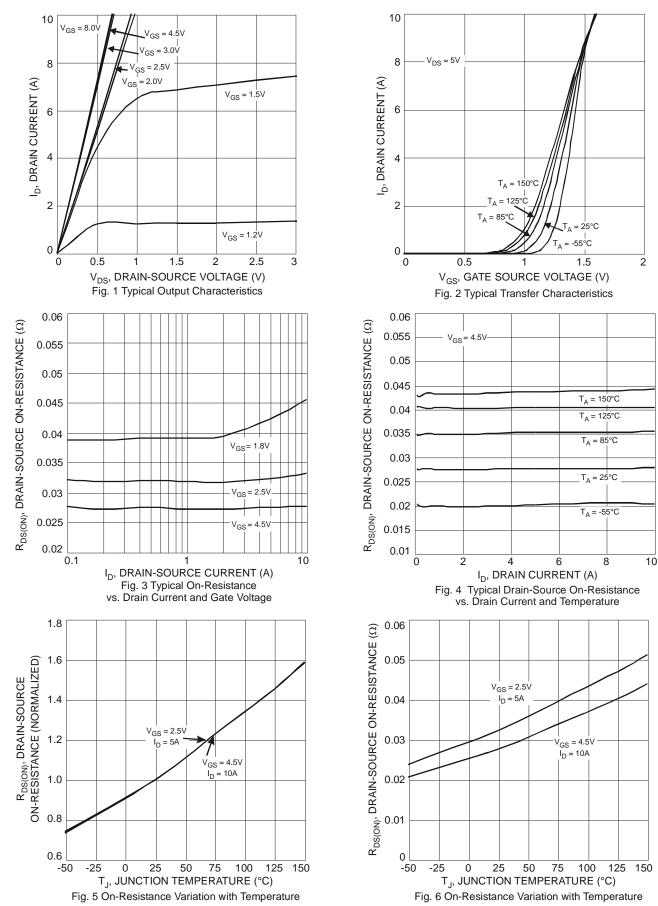
Electrical Characteristics (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV _{DSS}	20	-	-	V	$V_{GS} = 0V, I_D = 10\mu A$
Zero Gate Voltage Drain Current TJ = +25°C	IDSS	Ι	-	1.0	μA	$V_{DS} = 20V, V_{GS} = 0V$
Gate-Source Leakage	Igss	-	-	±100	nA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V _{GS(th)}	0.4	-	1.0	V	$V_{DS} = V_{GS}, I_D = 50 \mu A$
Static Drain-Source On-Resistance	Decision			90	mΩ	$V_{GS} = 4.5V, I_D = 3.6A$
	R _{DS} (ON)	-	_	120	11152	$V_{GS} = 2.5V, I_D = 3.1A$
Forward Transfer Admittance	Y _{fs}	-	13	-	S	$V_{DS} = 5V, I_D = 3.6A$
Diode Forward Voltage	V _{SD}	-	0.75	1.0	V	$V_{GS} = 0V, I_{S} = 1A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss	-	594.3	-	pF	
Output Capacitance	C _{oss}	Ι	64.5	-	pF	$V_{DS} = 10V, V_{GS} = 0V,$ f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}	-	57.7	-	pF	1 - 1.00012
Gate Resistance	Rg	-	1.5	-	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$
Total Gate Charge	Qg	-	7.0	_	nC	
Gate-Source Charge	Q _{gs}	-	0.9	-	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$
Gate-Drain Charge	Q _{gd}	-	1.4	-	nC	$I_D = 3.6A$
Turn-On Delay Time	t _{D(on)}	-	7.4	-	ns	
Turn-On Rise Time	tr	-	9.8	_	ns	$V_{DD} = 10V, V_{GS} = 4.5V,$
Turn-Off Delay Time	t _{D(off)}	-	28.1	_	ns	$R_L = 2.78\Omega, R_G = 1.0\Omega$
Turn-Off Fall Time	t _f	-	6.7	_	ns	

Notes:8. Short duration pulse test used to minimize self-heating effect.9. Guaranteed by design. Not subject to production testing.

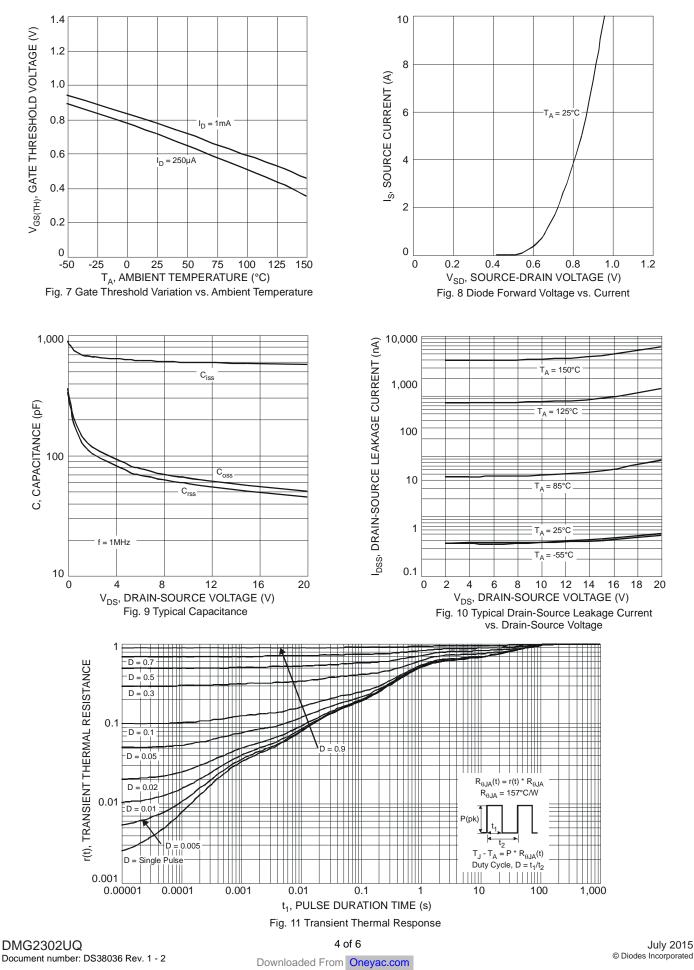


DMG2302UQ





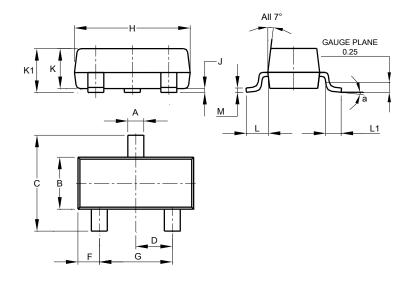
DMG2302UQ





Package Outline Dimensions

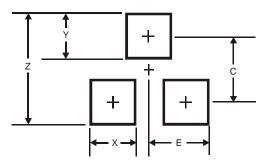
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT23							
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
ĸ	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
Μ	0.085	0.150	0.110					
α	8°							
All	All Dimensions in mm							

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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